# Octal 3-State Noninverting Buffer/Line Driver/Line Receiver

## **High-Performance Silicon-Gate CMOS**

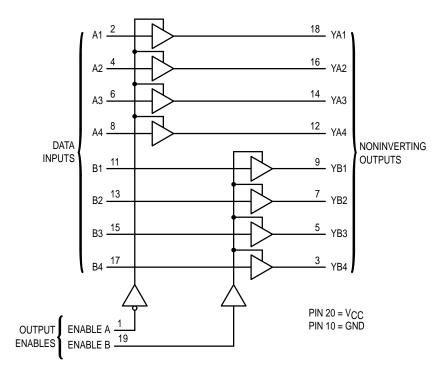
The MC54/74HC241A is identical in pinout to the LS241. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

This octal noninverting buffer/line driver/line receiver is designed to be used with 3-state memory address drivers, clock drivers, and other sub-oriented systems. The device has noninverted outputs and two output enables. Enable A is active-low and Enable B is active-high.

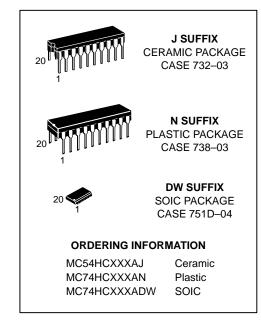
The HC241A is similar in function to the HC244A and HC240A.

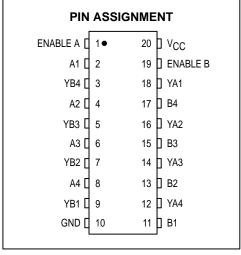
- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V
- Low Input Current: 1 μA
- · High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 134 FETs or 33.5 Equivalent Gates

#### LOGIC DIAGRAM



# MC54/74HC241A





FUNCTION TABLE								
Inputs Output Inputs Output								
Enable A	Α	YA	Enable B B		YB			
L	L	L	Н	L	L			
L	∟  н  н   н							
H   X   Z   L   X   Z								
Z = high i	Z = high impedance							



#### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
VCC	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> + 0.5	V
lin	DC Input Current, per Pin	± 20	mA
l <sub>out</sub>	DC Output Current, per Pin	± 35	mA
ICC	DC Supply Current, V <sub>CC</sub> and GND Pins	± 75	mA
PD	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package†	750 500	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) (Ceramic DIP)	260 300	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq$  ( $V_{in}$  or  $V_{out}$ )  $\leq$  VCC. Unused inputs must always be

tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

Ceramic DIP: - 10 mW/°C from 100° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Max	Unit
VCC	DC Supply Voltage (Referenced to GND)			6.0	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)		0	Vcc	V
TA	Operating Temperature, All Package Types		- 55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time VCC (Figure 1) VCC VCC	99		1000 500 400	ns

#### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Guaranteed Limit			
Symbol	Parameter	Test Conditions	v <sub>CC</sub>	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High–Level Input Voltage	$V_{\text{Out}} = V_{\text{CC}} - 0.1 \text{ V}$ $ I_{\text{Out}}  \le 20 \mu\text{A}$	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
VIL	Maximum Low–Level Input Voltage	$V_{\text{Out}} = 0.1 \text{ V}$ $ I_{\text{Out}}  \le 20 \mu\text{A}$	2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	V
VOH	Minimum High–Level Output Voltage	$V_{in} = V_{IH}$ $ I_{out}  \le 20 \mu\text{A}$	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$V_{\text{in}} = V_{\text{IH}}$ $  V_{\text{out}}   \le 2.4 \text{ mA}$ $  V_{\text{out}}   \le 6.0 \text{ mA}$ $  V_{\text{out}}   \le 7.8 \text{ mA}$	4.5	2.48 3.98 5.48	2.34 3.84 5.34	2.2 3.7 5.2	
VOL	Maximum Low–Level Output Voltage	$V_{in} = V_{IL}$ $ I_{out}  \le 20 \mu\text{A}$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$\begin{aligned} V_{\text{in}} = V_{\text{IL}} &  I_{\text{out}}  \leq 2.4 \text{ mA} \\  I_{\text{out}}  \leq 6.0 \text{ mA} \\  I_{\text{out}}  \leq 7.8 \text{ mA} \end{aligned}$	4.5	0.26 0.26 0.26	0.33 0.33 0.33	0.4 0.4 0.4	

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

<sup>†</sup>Derating — Plastic DIP: – 10 mW/ $^{\circ}$ C from 65 $^{\circ}$  to 125 $^{\circ}$ C

### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Guaranteed Limit			
Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
l <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = V <sub>CC</sub> or GND	6.0	± 0.1	± 1.0	± 1.0	μΑ
loz	Maximum Three–State Leakage Current	Output in High–Impedance State $V_{in} = V_{IL}$ or $V_{IH}$ $V_{out} = V_{CC}$ or GND	6.0	± 0.5	± 5.0	± 10	μА
lcc	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0 \mu A$	6.0	4.0	40	160	μΑ

NOTE: Information on typical parametric values along with high frequency or heavy load considerations, can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

#### AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , Input $t_f = t_f = 6.0 \text{ ns}$ )

			Gu	Guaranteed Limit		
Symbol	Parameter	v <sub>CC</sub>	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
tPLH, tPHL	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 3)	2.0 3.0 4.5 6.0	90 45 18 15	115 60 23 20	135 70 27 23	ns
<sup>t</sup> PLZ <sup>,</sup> <sup>t</sup> PHZ	Maximum Propagation Delay, Output Enable to Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	120 60 24 20	150 70 30 26	180 80 36 31	ns
<sup>t</sup> PZL <sup>,</sup> <sup>t</sup> PZH	Maximum Propagation Delay, Output Enable to Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	90 60 18 15	115 70 23 20	135 80 27 23	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 3)	2.0 3.0 4.5 6.0	60 23 12 10	75 27 15 13	90 32 18 15	ns
C <sub>in</sub>	Maximum Input Capacitance	_	10	10	10	pF
C <sub>out</sub>	Maximum Three–State Output Capacitance (Output in High–Impedance State)	_	15	15	15	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

		Typical @ 25°C, $V_{CC} = 5.0 \text{ V}$	
C <sub>PD</sub>	Power Dissipation Capacitance (Per Transceiver Channel)*	34	pF

<sup>\*</sup> Used to determine the no–load dynamic power consumption:  $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$ . For load considerations, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

3

#### **SWITCHING WAVEFORMS**

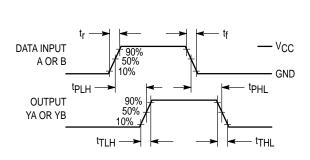
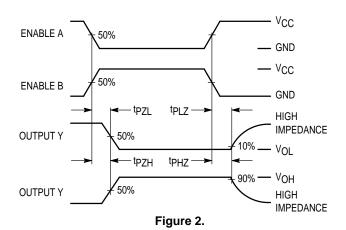
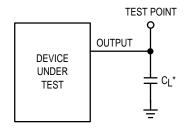


Figure 1.





<sup>\*</sup> Includes all probe and jig capacitance

 $\begin{array}{c|c} & \text{TEST POINT} \\ \hline \\ \text{DEVICE} \\ \text{UNDER} \\ \text{TEST} \end{array} \begin{array}{c} \text{OUTPUT} \\ \text{OUTPUT} \\ \text{TEST ING tp}_{LZ} \text{ AND tp}_{LL}. \\ \text{CONNECT TO GND WHEN} \\ \text{TESTING tp}_{HZ} \text{ AND tp}_{ZH}. \\ \hline \\ \text{TEST ING tp}_{HZ} \text{ AND tp}_{ZH}. \\ \hline \end{array}$ 

Figure 3. Test Circuit

Figure 4. Test Circuit

#### **PIN DESCRIPTIONS**

#### **INPUTS**

A1, A2, A3, A4, B1, B2, B3, B4 (Pins 2, 4, 6, 8, 11, 13, 15, 17)

Data input pins. Data on these pins appear in noninverted form on the corresponding Y outputs when the outputs are enabled.

#### **CONTROLS**

#### Enable A (Pin 1)

Output enable (active—low). When a low level is applied to this pin, the outputs of the "A" devices are enabled and the devices function as noninverting buffers. When a high level is applied, the outputs assume the high—impedance state.

#### Enable 8 (Pin 19)

Output enable (active—high). When a high level is applied to this pin, the outputs of the "B" devices are enabled and the devices function as noninverting buffers. When a low level is applied, the outputs assume the high—impedance state.

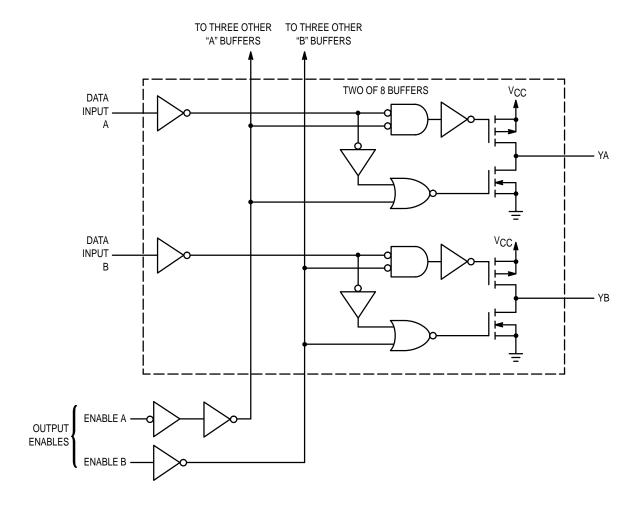
#### **OUTPUTS**

YA1, YA2, YA3, YA4, YB1, YB2, YB3, YB4 (Pins 18, 16, 14, 12, 9, 7, 5, 3)

Device outputs. Depending upon the state of the outputenable pins, these outputs are either noninverting outputs or high-impedance outputs.

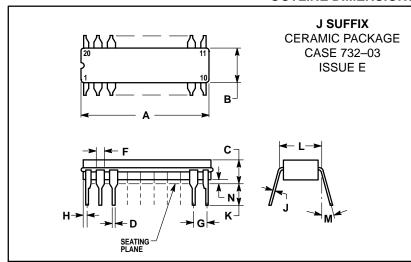
<sup>\*</sup> Includes all probe and jig capacitance

## **LOGIC DETAIL**



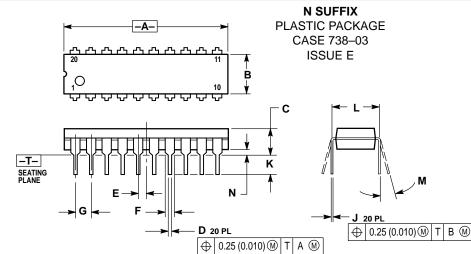
5

#### **OUTLINE DIMENSIONS**



- LEADS WITHIN 0.25 (0.010) DIAMETER, TRUE
   POSITION AT SEATING PLANE, AT MAXIMUM
   MATERIAL CONDITION.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- 3. DIMENSIONS A AND B INCLUDE MENISCUS.

	MILLIN	METERS	S INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	23.88	25.15	0.940	0.990	
В	6.60	7.49	0.260	0.295	
С	3.81	5.08	0.150	0.200	
D	0.38	0.56	0.015	0.022	
F	1.40	1.65	0.055	0.065	
G	2.54 BSC		0.100	BSC	
Н	0.51	1.27	0.020	0.050	
J	0.20	0.30	0.008	0.012	
K	3.18	4.06	0.125	0.160	
L	7.62	BSC	0.300 BSC		
М	0 °	15°	0°	15°	
N	0.25	1.02	0.010	0.040	



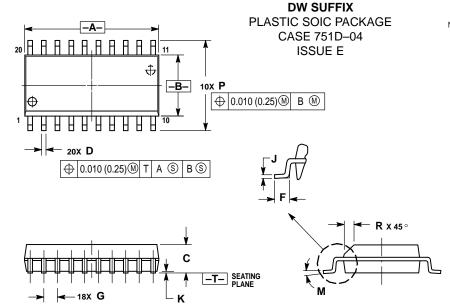
#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN

- FORMED PARALLEL.

  4. DIMENSION B DOES NOT INCLUDE MOLD

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.010	1.070	25.66	27.17
В	0.240	0.260	6.10	6.60
С	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
Е	0.050	BSC	1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100	BSC	2.54 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62	BSC
М	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01



- OTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

  4. MAXIMUM MOLD PROTRUSION 0.150
- (0.006) PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	12.65	12.95	0.499	0.510
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050	BSC
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
М	0 °	7 °	0 °	7°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights or others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and was negligent regarding the design or manufacture of the part. Motorola and are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Mfax is a trademark of Motorola, Inc.

#### How to reach us:

**USA/EUROPE/Locations Not Listed**: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447

**JAPAN**: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 81–3–3521–8315

**Mfax**™: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 – US & Canada ONLY 1–800–774–1848

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

INTERNET: http://www.mot.com/SPS/



MC74HC241A/D

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.